
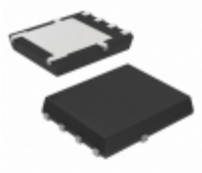
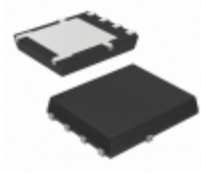
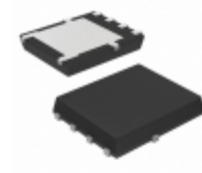
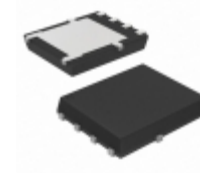
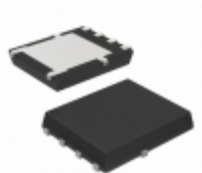
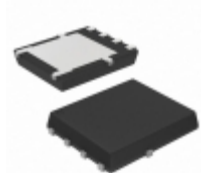
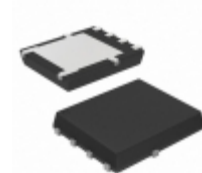
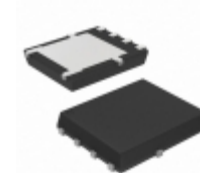
	<h2 style="color: #E67E22;">NVMFS4C01NWFT1G</h2>
	<p>Hersteller-Teilenummer: NVMFS4C01NWFT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 49A SO8FL</p> <p>Datenblätter:  NVMFS4C01NWFT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 11967 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMFS4C01NWFT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 49A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	11967 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	3.84W (Ta), 161W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	49A (Ta), 319A (Tc)
Rds On (Max) @ Id, Vgs	0.9 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	139nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	10144pF @ 15V
Verpackung	Tape & Reel (TR)


























NVMFS4C01NWFT1G ist neu im Original, Suche NVMFS4C01NWFT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVMFS4C01NWFT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVMFS4C01NWFT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NVMFS4C03NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 31.4A SO8FL</p>	 <p>NVMFS4C03NWFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 31.4A SO8FL</p>	 <p>NVMFS4C01NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 49A SO8FL</p>	 <p>NVMFS4841NWFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 89A SO8FL</p>
 <p>NVMFS4841NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 89A SO-8FL</p>	 <p>NVMFS4C03NWFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 31.4A SO8FL</p>	 <p>NVMFS4C01NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 49A SO8FL</p>	 <p>NVMFS4C01NWFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 49A SO8FL</p>

heiße Teile

Mehr

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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